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Divergences of the localization lengths in the two-dimensional, off-diagonal Anderson model on bipartite lattices

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1. Introduction

The disorder-induced metal-insulator transition (MIT) and the concept of Anderson localization[1–5] has been the subject of intense research activities for more than forty years. The scaling theory of localization[6] predicts that for generic, interaction-free situations in 2D all states are localized; there is no disorder-driven MIT[7–9] and the system remains an insulator. However, non-localized states were found at the band center of an Anderson model with purely off-diagonal disorder.[10–14] Numercal studies of such systems revealed that the localization length diverges at the energy $E = 0$.[15,16] Scaling properties of this divergence suggest that the states at the band center are critical[16,17] and that are indeed no truly extended states in 2D even in this off-diagonal case.

Of special importance is the model on a bipartite lattice with an even number of sites where the energy spectrum is strictly symmetric around $E = 0$. In this case, related to the chiral universality class, $E = 0$ states are non-localized in any dimension.[18–20] This has been recently demonstrated analytically in 2D and 3D using a renormalization group (RG) approach.[21] In Ref.[21] it has been also suggested that for sufficiently large energies the divergence of the localization length at the band center may be described by a power law,

$$\xi(E) \propto \left| \frac{E_0}{E} \right|^{\nu} \tag{1}$$

whereas it takes more complicated form

$$\xi(E) \propto \exp \sqrt{\frac{\ln E_0/E}{A}} \tag{2}$$

below a certain crossover energy E^*.

Recently[22] we studied such 2D bipartite systems with various types of off-diagonal disorder by means of the transfer-matrix method (TMM) and investigated the divergence of the localization length close to $E = 0$. We showed that the data fit the power-low behaviour down to energy $E = 2 \times 10^{-5}$ and the corresponding critical exponents seem to depend on the type of disorder distribution and strength. Here we extend these results to even smaller energies and examine honeycomb lattices where the Van Hove singularity at $E = 0$ does not interfere with the divergence due to the bipartiteness.

2. Computation of the localization lenghts and the critical exponents

We considered a single electron on a 2D lattce described by the Hamiltonian

$$H = \sum_{i \neq j}^{N} t_{ij} \left| i \right\rangle \left\langle j \right| \tag{3}$$

where $|i\rangle$ denotes the electron at site i. The off-diagonal disorder was introduced by *random* hopping elements t_{ij} between nearest neighbor sites. We considered bipartite square and honeycomb lattices. The latter is topologically equivalent to a brick-layer structure,[23] which implies that one of the connections to the nearest-neighbor is absent — the corresponding hopping element is equal to 0.

On both lattices we examined three different distributions of the off-diagonal elements t_{ij}:

(1) a rectangular distribution[15]

$$P(t_{ij}) = \begin{cases} 1/w & \text{if } |t_{ij} - c| \leq w/2, \\ 0 & \text{otherwise,} \end{cases}$$

(2) a Gaussian distribution

$$P(t_{ij}) = \frac{1}{\sqrt{2\pi\sigma^2}} \exp\left[-\frac{(t_{ij} - c)^2}{2\sigma^2} \right],$$

(3) a rectangular distribution of the logarithm of t_{ij}[14]

$$P(\ln t_{ij}/t_0) = \begin{cases} 1/w & \text{if } |\ln t_{ij}/t_0| \leq w/2, \\ 0 & \text{otherwise.} \end{cases}$$

In the case of rectangular and Gaussian distributions of hopping elements we have set the width w and the standard deviation σ of the distribution to 1 and centered it at $c = 0$. In the case of logarithmic-t distribution we chose $t_0 = 1$ which set the energy scale and performed the calculations for two values of the distribution width, e.g., $w = 2$ and 6.

We used the transfer-matrix method[24,25] to compute the localization lengths for strips of widths M up to 220 in the energy interval $10^{-8} \leq E \leq 0.1$, the actual values depend on the disorder parameters. The accuracy of the results was 1%. Next, finite-size scaling[25] was applied to the data. We used M as large as possible in order

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to avoid problems related to the finite-size effects. For some cases this imposes the restriction on the smallest energies which we were able to use in FSS.

To investigate the divergence of the localization lenghts at the band center we plotted the scaling parameter ξ in a double-logarithmic plot. The deviation of the divergence from the power-law behaviour should then be easily seen. In most cases we observed that at the energies close to $E = 0$ the divergence is slower than described by a power-law. However, these deviations get smaller when we increase widths M of the systems used in FSS (an example of such behaviour is shown in Fig. 1), therefore we relate them to finite-size effects.

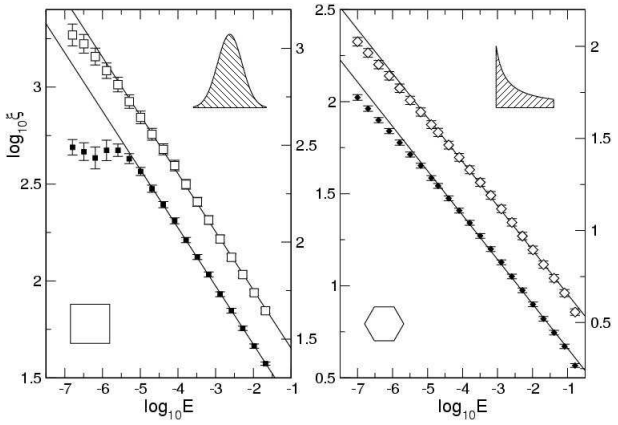


Fig. 1. Scaling parameter ξ vs. energy. Left panel: square lattice, Gaussian distribution ($\sigma = 1$, $c = 0$), right panel: honeycomb lattice, logarithmic t distribution ($w = 6$); filled symbols: results for $M = 50$–100, open symbols: results for $M = 110$–160 (Gaussian distribution) or $M = 100$–150 (logarithmic distribution).

3. Results and disussions

In Table I we collected the critical exponents obtained for different lattices and disorder distributions. All values are in the range of $0.2 - 0.6$ and depend on the disorder type. Generally the exponents are larger for weaker disorders (i.e. when the localization lengths are larger). The differences between square and honeycomb lattice in most cases do not exceed the accuracy of the results. The exception is the logarithmic t distribution with $w = 2$, when the exponent is almost 2 times larger on a honeycomb lattice. The large change in the exponent may be related to the low density of states on a honeycomb lattice, where the van Hove singularity in the density of states is absent.

The localization lengths exhibit power-law behaviour in a wide energy range, the lower lower bound $E_{\min}$ of which is indicated in Table I. For smaller energies we observe some deviations, however, these become smaller for larger system widths M we would argue that these are finite-size effects that will eventually vanish if one uses large enough system sizes. The exception to this behaviour is the logarithmic-t disribution for $w = 6$, where below an energy $E \approx 10^{-5}$ the deviation from power law seems to be size independent. This may be an indication of the crossover to the non-power-law behavior as predicted in Ref.[21] or to a power-law with a different exponent. However, there is also a possibilty that this may be an effect of numerical problems which appear for strong logarithmic disorders.

Table I. Estimated values of the exponents ν of the localization lengths for various disorder strengths and distributions. The range of the strip widths M is displayed in the second column; the power-law behaviour is obeyed in the energy ranging from E_{min} up to 1×10^{-2}. The error bars represent the standard deviations from the power-law fit and should be increased up to one order of magnitude for a reliable representation of the actual errors.

square lattice

disorder	M	$E_{\min}$	ν
box, $c = 0$	$150 - 220$	8×10^{-7}	0.317 ± 0.007
Gaussian, $c = 0$	$110 - 160$	2×10^{-6}	0.303 ± 0.006
lnt, $w = 2$	$110 - 190$	2×10^{-6}	0.357 ± 0.009
lnt, $w = 6$	$120 - 170$	1×10^{-5}	0.232 ± 0.007

honeycomb lattice

disorder	M	$E_{\min}$	ν
box, $c = 0$	$110 - 170$	2×10^{-8}	0.290 ± 0.004
Gaussian, $c = 0$	$120 - 170$	1×10^{-6}	0.273 ± 0.005
lnt, $w = 2$	$100 - 170$	2×10^{-4}	0.604 ± 0.015
lnt, $w = 6$	$120 - 170$	1×10^{-5}	0.238 ± 0.007

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